Automotive P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	-60
$R_{DS(on)}$ (Ω) at V_{GS} = -10 V	0.0093
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0133
I_D (A)	-100
Configuration	Single

FEATURES

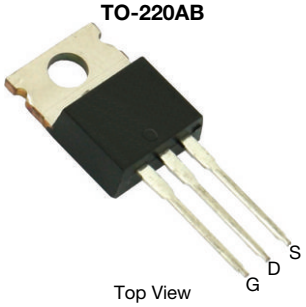
- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified [d]
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

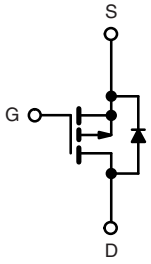
RoHS COMPLIANT

HALOGEN FREE

TO-220AB



Top View



P-Channel MOSFET

ORDERING INFORMATION	
Package	TO-220
Lead (Pb)-free and Halogen-free	SQP100P06-9m3L-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	-60	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	T_C = 25 °C	I_D	-100	A
	T_C = 125 °C		-58	
Continuous Source Current (Diode Conduction) [a]		I_S	-120	
Pulsed Drain Current [b]		I_{DM}	-300	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	-70	
Single Pulse Avalanche Energy		E_{AS}	245	mJ
Maximum Power Dissipation [b]	T_C = 25 °C	P_D	187	W
	T_C = 125 °C		62	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount [c]	R_{thJA}	40	°C/W
Junction-to-Case (Drain)		R_{thJC}	0.8	

Notes

a. Package limited.
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
c. When mounted on 1" square Pcb (Fr-4 material).
d. Parametric verification ongoing.

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0, I_D = -250 µA		-60	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA		-1.5	-2.0	-2.5	
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V	V_{DS} = -60 V	-	-	-1	µA
		V_{GS} = 0 V	V_{DS} = -60 V, T_J = 125 °C	-	-	-50	
		V_{GS} = 0 V	V_{DS} = -60 V, T_J = 175 °C	-	-	-250	
On-State Drain Current [a]	$I_{D(on)}$	V_{GS} = -10 V	V_{DS} ≤ -5 V	-100	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V	I_D = -30 A	-	0.0072	0.0093	Ω
		V_{GS} = -10 V	I_D = -30 A, T_J = 125 °C	-	-	0.0151	
		V_{GS} = -10 V	I_D = -30 A, T_J = 175 °C	-	-	0.0184	
		V_{GS} = -4.5 V	I_D = -20 A	-	0.0102	0.0133	
Forward Transconductance [b]	g_{fs}	V_{DS} = -15 V, I_D = -30 A		-	82	-	S
Dynamic [b]							
Input Capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = -25 V, f = 1 MHz	-	9605	12 010	pF
Output Capacitance	C_{oss}			-	1030	1290	
Reverse Transfer Capacitance	C_{rss}			-	750	940	
Total Gate Charge [c]	Q_g	V_{GS} = -10 V	V_{DS} = -30 V, I_D = -100 A	-	198	300	nC
Gate-Source Charge [c]	Q_{gs}			-	30	-	
Gate-Drain Charge [c]	Q_{gd}			-	54	-	
Gate Resistance	R_g	f = 1 MHz		1	2.2	3.5	Ω
Turn-On Delay Time [c]	$t_{d(on)}$	V_{DD} = -30 V, R_L = 0.3 Ω I_D ≅ -100 A, V_{GEN} = -10 V, R_g = 1 Ω		-	18	30	ns
Rise Time [c]	t_r			-	12	20	
Turn-Off Delay Time [c]	$t_{d(off)}$			-	85	130	
Fall Time [c]	t_f			-	36	55	
Source-Drain Diode Ratings and Characteristics [b]							
Pulsed Current [a]	I_{SM}			-	-	-300	A
Forward Voltage	V_{SD}	I_F = -80 A, V_{GS} = 0		-	-0.95	-1.5	V

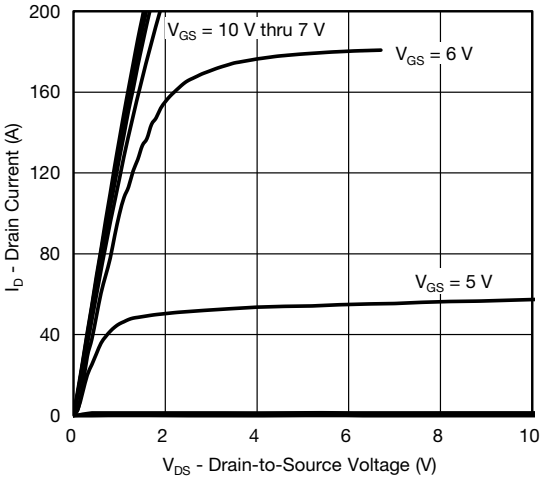
Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

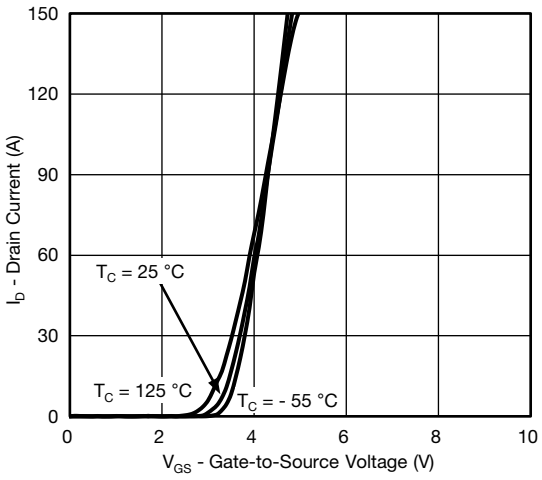
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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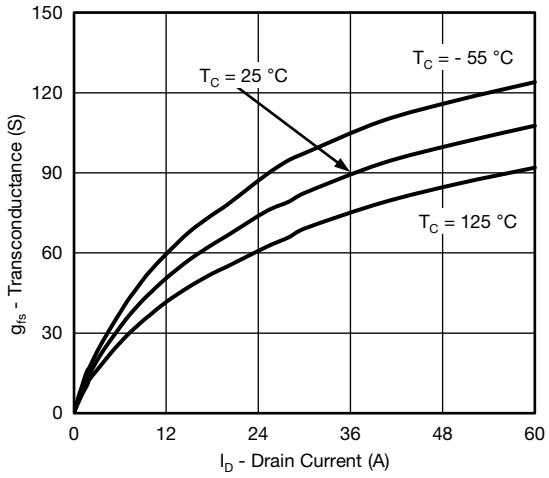
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



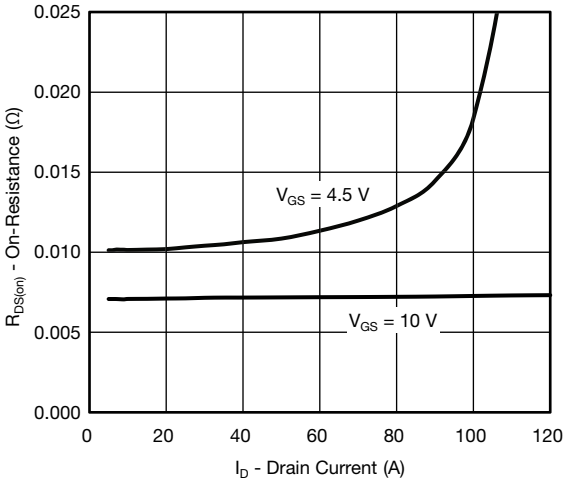
Output Characteristics



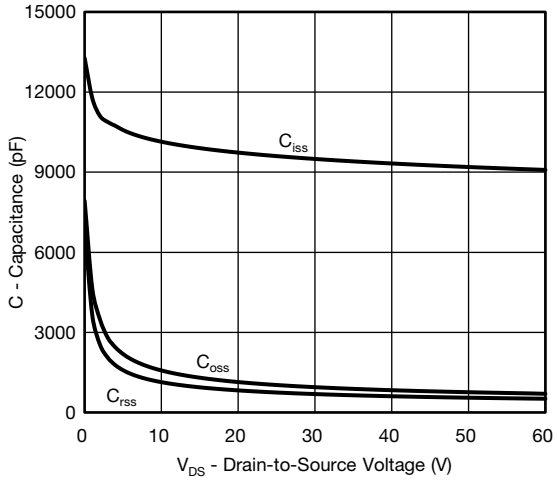
Transfer Characteristics



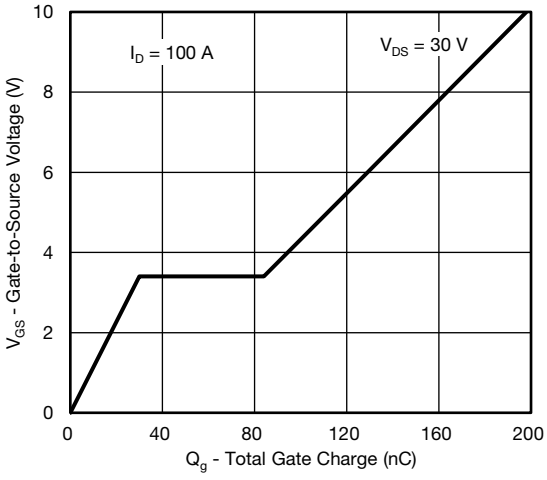
Transconductance



On-Resistance vs. Drain Current



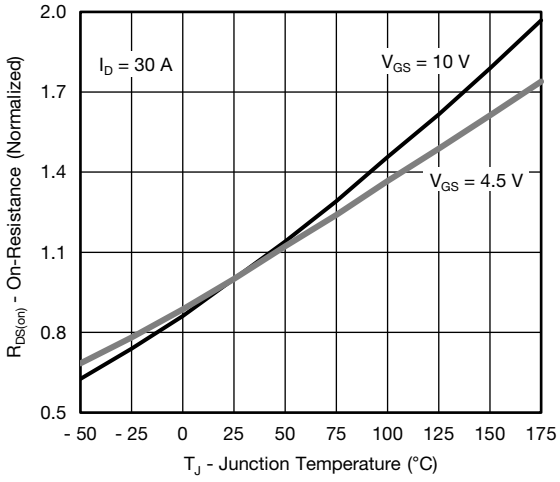
Capacitance



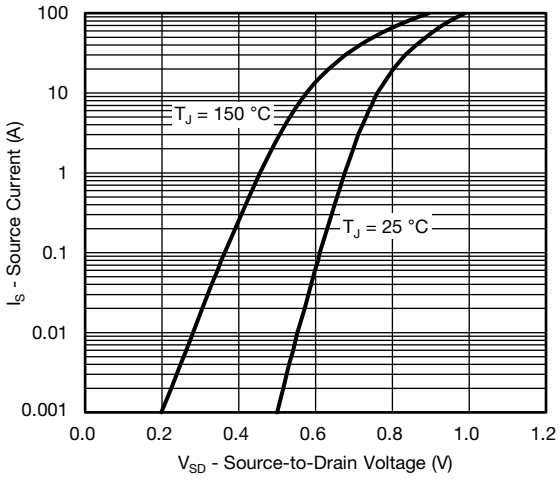
Gate Charge

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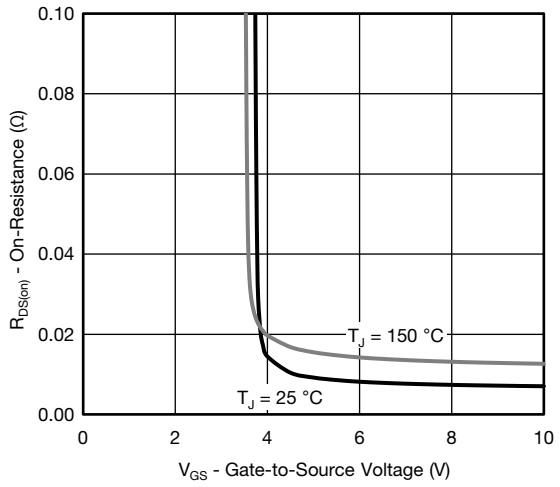
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



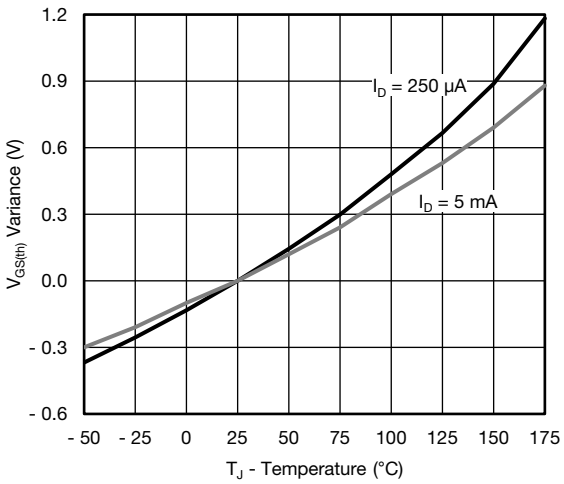
On-Resistance vs. Junction Temperature



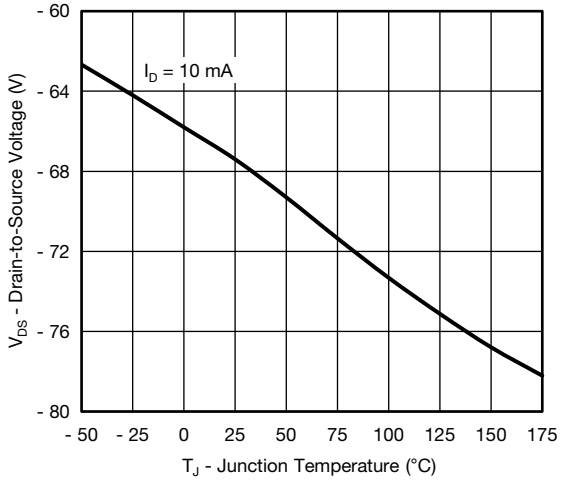
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



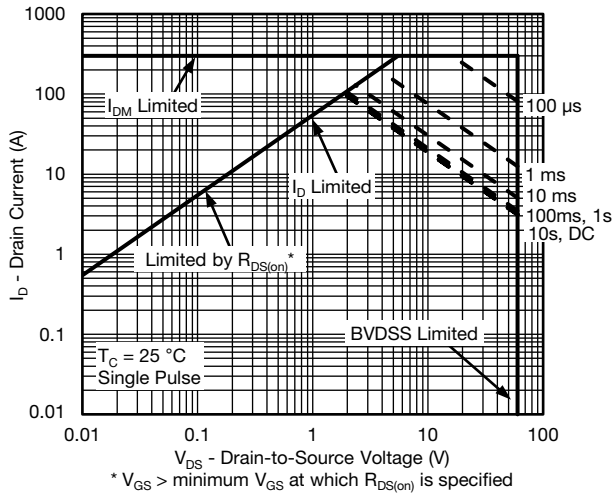
Threshold Voltage



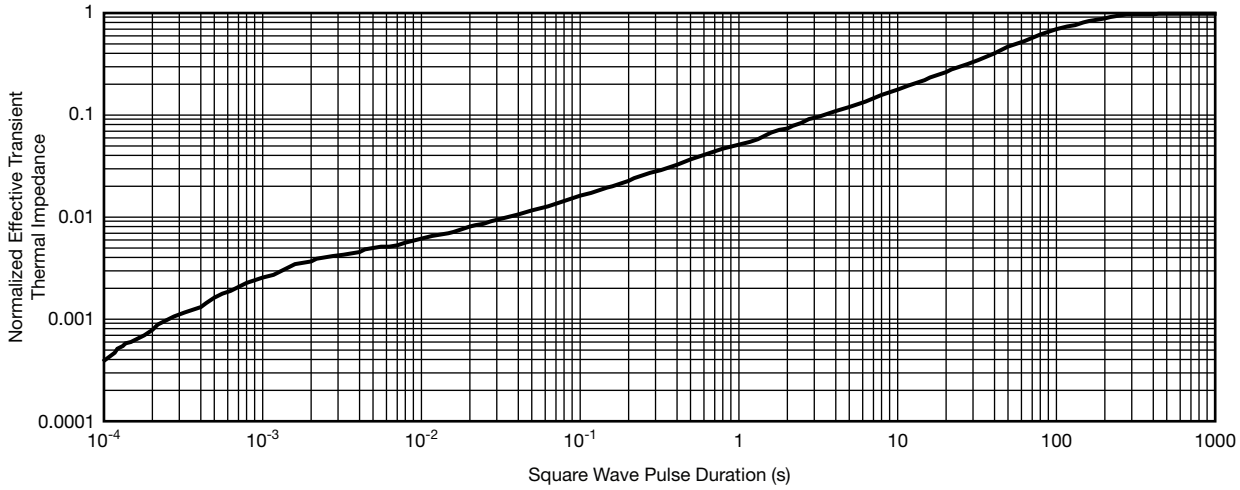
Drain Source Breakdown vs. Junction Temperature

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



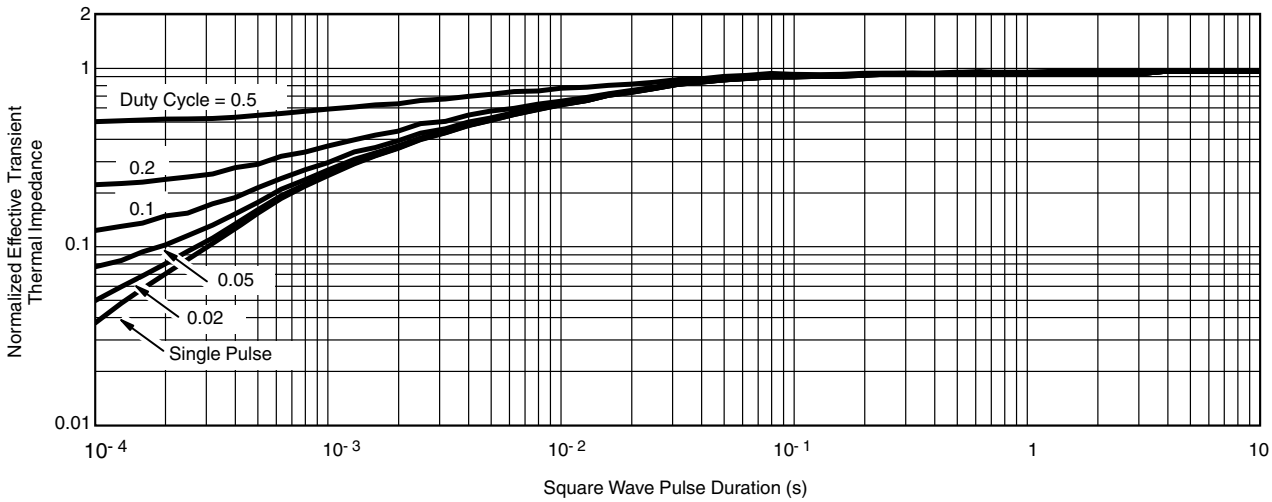
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

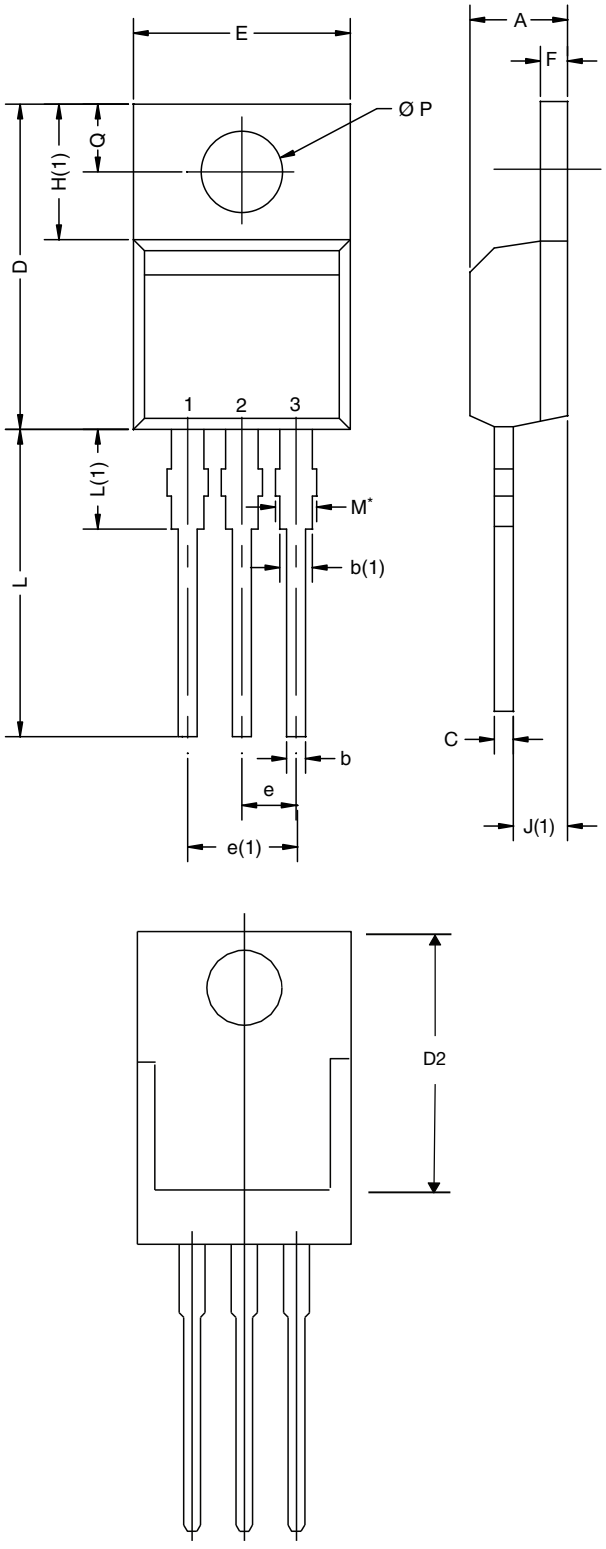
- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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TO-220AB



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
c	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
E	10.04	10.51	0.395	0.414
e	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
Ø P	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: T14-0413-Rev. P, 16-Jun-14 DWG: 5471				

Note

* M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM

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